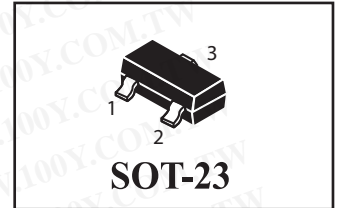
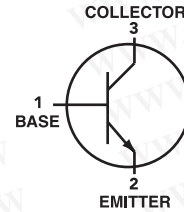


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**C945**

## NPN Transistors



### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CE0}$	50	Vdc
Collector-Base Voltage	$V_{CBO}$	60	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current-Continuous	$I_C$	150	mAdc

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (1) $T_A=25^{\circ}\text{C}$ Derate above $25^{\circ}\text{C}$	$P_D$	200	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	$^{\circ}\text{C/W}$
Junction and Storage, Temperature	$T_J, T_{stg}$	-55 to +150	$^{\circ}\text{C}$

### DEVICE MARKING

2SC945=CR

### ELECTRICAL CHARACTERISTICS

Characteristics	Symbol	Min	Max	Unit
-----------------	--------	-----	-----	------

### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ( $I_C=100\ \mu\text{Adc}, I_E=0$ )	$V_{(BR)CEO}$	50	-	Vdc
Collector-Base Breakdown Voltage ( $I_C=1\ \text{mAdc}, I_E=0$ )	$V_{(BR)CBO}$	60	-	Vdc
Emitter-Base Breakdown Voltage ( $I_E=100\ \mu\text{Adc}, I_C=0$ )	$V_{(BR)EBO}$	5.0	-	Vdc
Collector Cutoff Current ( $V_{CE}=60\ \text{Vdc}, I_E=0$ )	$I_{CEO}$	-	0.1	$\mu\text{Adc}$
Collector Cutoff Current ( $V_{CB}=45\ \text{Vdc}, I_E=0$ )	$I_{CBO}$	-	0.1	$\mu\text{Adc}$
Emitter Cutoff Current ( $V_{EB}=5.0\ \text{Vdc}, I_C=0$ )	$I_{EBO}$	-	0.1	$\mu\text{Adc}$

1.FR-5=1.0 x 0.75 x 0.062 in

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## ELECTRICAL CHARACTERISTICS ( $T_A=25^{\circ}\text{C}$ unless otherwise noted) (Countinued)

Characteristics	Symbol	Min	Typ	Max	Unit
-----------------	--------	-----	-----	-----	------

## ON CHARACTERISTICS

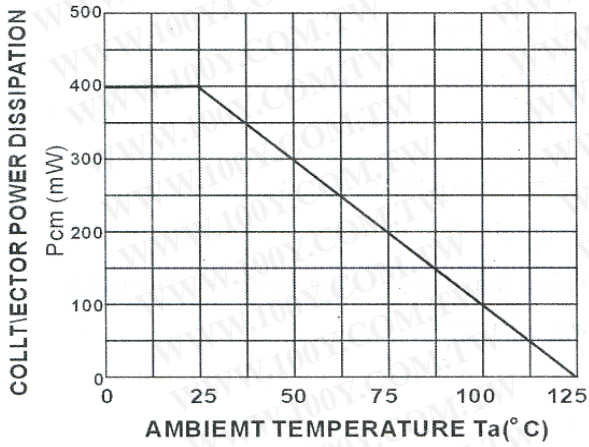
DC Current Gain ( $I_C=1\text{ mAdc}, V_{CE}=6.0\text{ Vdc}$ )	$h_{FE}$	130	-	400	-
Collector-Emitter Saturation Voltage ( $I_C=100\text{ mAdc}, I_B=10\text{ mAdc}$ )	$V_{CE(sat)}$	-	-	0.3	Vdc
Base-Emitter Voltage ( $I_E=310\text{ mA}$ )	$V_{BEF}$	-	-	1.4	V
Transition Frequency ( $I_C=-10\text{ mAdc}, V_{CE}=6\text{ Vdc}, f=30\text{ MHz}$ )	$f_T$	150	-	-	MHz

## CLASSIFICATION OF $h_{FE}$

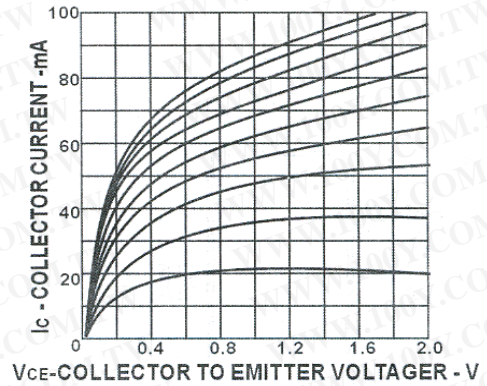
Rank	L	H
Range	130-200	200-400

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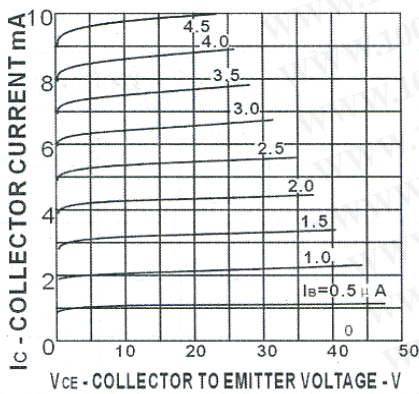
# C945



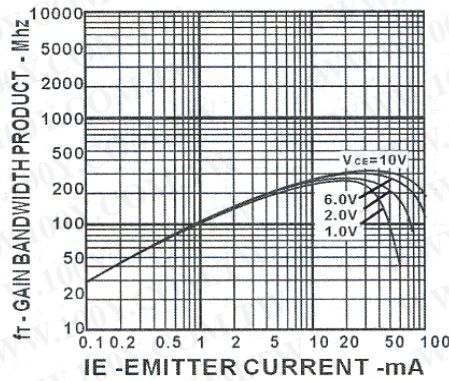
**FIG1. Total Power Dissipation vs Ambient Temperature**



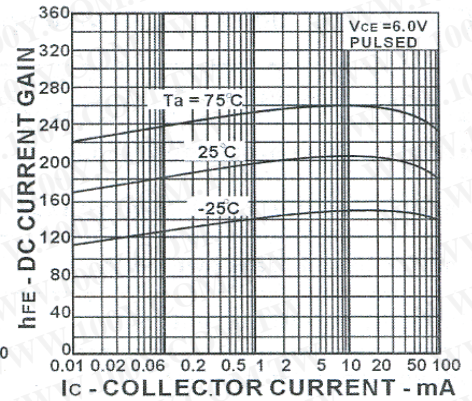
**FIG2. Collector Current vs Collector to Emitter Voltage**



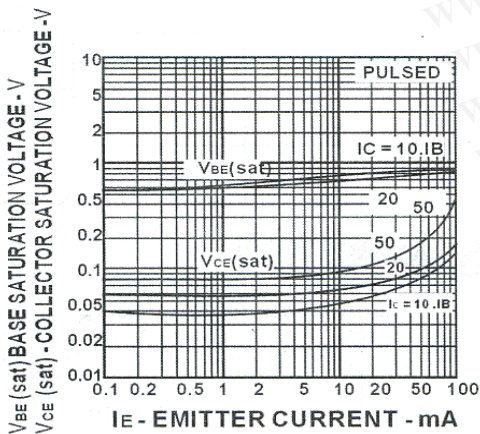
**FIG.3 Collector Current vs Collector to Emitter Voltage**



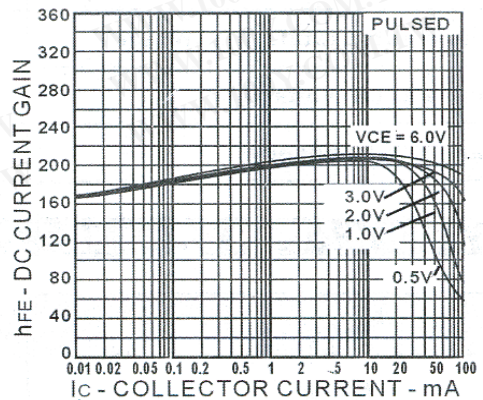
**FIG.4 Gain Bandwidth Product vs Emitter Current**



**FIG.5 DC Current Gain vs Collector Current**



**FIG.6 Collector and Base Saturation Voltage vs Collector Current**



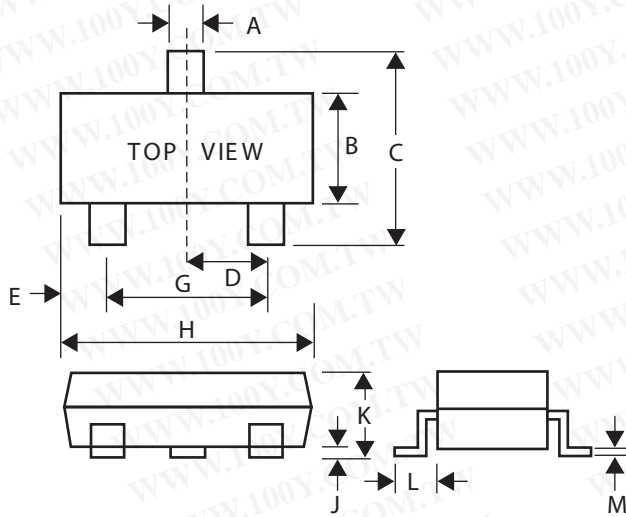
**FIG.7 DC Current Gain vs Collector Current**

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**C945**

**SOT-23 Package Outline Dimensions**

Unit:mm



Dim	Min	Max
A	0.35	0.51
B	1.19	1.40
C	2.10	3.00
D	0.85	1.05
E	0.46	1.00
G	1.70	2.10
H	2.70	3.10
J	0.01	0.13
K	0.89	1.10
L	0.30	0.61
M	0.076	0.25